

FEATURES

Operating RF frequency

30 MHz to 2 GHz

LO input at $2 \times f_{LO}$

60 MHz to 4 GHz

Input IP3: 31 dBm at 900 MHz

Input IP2: 62 dBm at 900 MHz

Input P1dB: 13 dBm at 900 MHz

Noise figure (NF)

12.0 dB at 140 MHz

14.7 dB at 900 MHz

Voltage conversion gain > 4 dB

Quadrature demodulation accuracy

Phase accuracy $\sim 0.4^\circ$

Amplitude balance ~ 0.05 dB

Demodulation bandwidth ~ 240 MHz

Baseband I/Q drive 2 V p-p into 200 Ω

Single 5 V supply

APPLICATIONS

QAM/QPSK RF/IF demodulators

W-CDMA/CDMA/CDMA2000/GSM

Microwave point-to-(multi)point radios

Broadband wireless and WiMAX

Broadband CATVs

GENERAL DESCRIPTION

The [ADL5387](#) is a broadband quadrature I/Q demodulator that covers an RF/IF input frequency range from 30 MHz to 2 GHz. With a NF = 13.2 dB, IP1dB = 12.7 dBm, and IIP3 = 32 dBm at 450 MHz, the [ADL5387](#) demodulator offers outstanding dynamic range suitable for the demanding infrastructure direct-conversion requirements. The differential RF/IF inputs provide a well-behaved broadband input impedance of 50 Ω and are best driven from a 1:1 balun for optimum performance.

Ultrabroadband operation is achieved with a divide-by-2 method for local oscillator (LO) quadrature generation. Over a wide range of LO levels, excellent demodulation accuracy is achieved with amplitude and phase balances ~ 0.05 dB and $\sim 0.4^\circ$, respectively. The demodulated in-phase (I) and quadrature (Q) differential outputs are fully buffered and provide a voltage conversion gain of >4 dB. The buffered baseband outputs are capable of driving a 2 V p-p differential signal into 200 Ω .

FUNCTIONAL BLOCK DIAGRAM

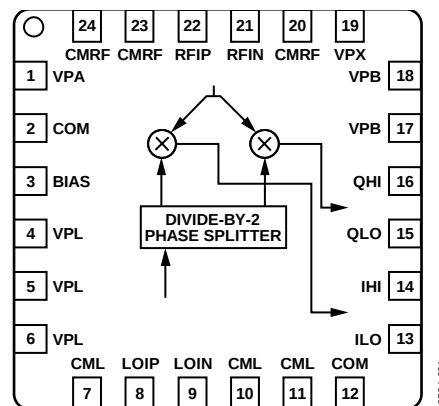


Figure 1.

The fully balanced design minimizes effects from second-order distortion. The leakage from the LO port to the RF port is < -70 dBc. Differential dc-offsets at the I and Q outputs are < 10 mV. Both of these factors contribute to the excellent IIP2 specifications > 60 dBm.

The [ADL5387](#) operates off a single 4.75 V to 5.25 V supply. The supply current is adjustable with an external resistor from the BIAS pin to ground.

The [ADL5387](#) is fabricated using the Analog Devices, Inc., advanced silicon-germanium bipolar process and is available in a 24-lead exposed paddle LFCSP.

Rev. B

Document Feedback

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

TABLE OF CONTENTS

Features	1	Mixers	15
Applications	1	Emitter Follower Buffers	15
Functional Block Diagram	1	Bias Circuit	15
General Description	1	Applications Information	16
Revision History	2	Basic Connections	16
Specifications	3	Power Supply	16
Absolute Maximum Ratings	5	Local Oscillator (LO) Input	16
ESD Caution	5	RF Input	17
Pin Configuration and Function Descriptions	6	Baseband Outputs	17
Typical Performance Characteristics	7	Error Vector Magnitude (EVM) Performance	18
Distributions for $f_{RF} = 140$ MHz	11	Low IF Image Rejection	19
Distributions for $f_{RF} = 450$ MHz	12	Example Baseband Interface	19
Distributions for $f_{RF} = 900$ MHz	13	Characterization Setups	22
Distributions for $f_{RF} = 1900$ MHz	14	Evaluation Board	24
Circuit Description	15	Outline Dimensions	27
LO Interface	15	Ordering Guide	27
V-to-I Converter	15		

REVISION HISTORY

10/13—Rev. A to Rev. B

Added Figure 4, Figure 6, and Figure 8; Renumbered Sequentially	7
Moved Figure 9, Added Figure 10	8
Changes to Figure 25	11
Changes to Figure 31	12
Updated Outline Dimensions	27
Changes to Ordering Guide	27

5/13—Rev. 0 to Rev. A

Changed Minimum Operating RF Frequency from 50 MHz to 30 MHz (Throughout)	1
Changed Minimum LO Input at $2 \times f_{LO}$ from 100 MHz to 60 MHz (Throughout)	1
Added Dynamic Performance @ RF = 30 MHz Parameters	3
Changes to Local Oscillator (LO) Input Section	15
Changes to Table 4	24
Updated Outline Dimensions	26
Changes to Ordering Guide	26

10/07—Revision 0: Initial Version

SPECIFICATIONS

$V_S = 5\text{ V}$, $T_A = 25^\circ\text{C}$, $f_{RF} = 900\text{ MHz}$, $f_{IF} = 4.5\text{ MHz}$, $P_{LO} = 0\text{ dBm}$, BIAS pin open, $Z_O = 50\ \Omega$, unless otherwise noted, baseband outputs differentially loaded with $450\ \Omega$.

Table 1.

Parameter	Condition	Min	Typ	Max	Unit
OPERATING CONDITIONS					
LO Frequency Range	External input = 2xLO frequency	0.06		4	GHz
RF Frequency Range		0.03		2	GHz
LO INPUT					
Input Return Loss	LOIP, LOIN AC-coupled into LOIP with LOIN bypassed, measured at 2 GHz		–10		dB
LO Input Level		–6	0	+6	dBm
I/Q BASEBAND OUTPUTS					
Voltage Conversion Gain	QHI, QLO, IHI, ILO 450 Ω differential load on I and Q outputs (at 900 MHz)		4.3		dB
	200 Ω differential load on I and Q outputs (at 900 MHz)		3.2		dB
Demodulation Bandwidth	1 V p-p signal 3 dB bandwidth at 900 MHz		240		MHz
Quadrature Phase Error			0.4		Degrees
I/Q Amplitude Imbalance			0.1		dB
Output DC Offset (Differential)	0 dBm LO input		± 5		mV
Output Common-Mode			VPOS – 2.8		V
0.1 dB Gain Flatness			40		MHz
Output Swing	Differential 200 Ω load		2		V p-p
Peak Output Current	Each pin		12		mA
POWER SUPPLIES					
Voltage	VPA, VPL, VPB, VPX	4.75		5.25	V
Current	BIAS pin open RBIAS = 4 k Ω		180 157		mA mA
DYNAMIC PERFORMANCE at RF = 30 MHz					
Conversion Gain	RFIP, RFIN, L1, L2 = 680 nH, C10, C11 = 0.01 μF^1		4.5		dB
Input P1dB (IP1dB)			12		dBm
Second-Order Input Intercept (IIP2)	–5 dBm each input tone		69		dBm
Third-Order Input Intercept (IIP3)	–5 dBm each input tone		31		dBm
I/Q Magnitude Imbalance			0.1		dB
I/Q Phase Imbalance			0.3		Degrees
DYNAMIC PERFORMANCE at RF = 140 MHz					
Conversion Gain	RFIP, RFIN		4.7		dB
Input P1dB (IP1dB)			13		dBm
Second-Order Input Intercept (IIP2)	–5 dBm each input tone		67		dBm
Third-Order Input Intercept (IIP3)	–5 dBm each input tone		31		dBm
LO to RF	RFIN, RFIP terminated in 50 Ω , 1xLO appearing at the RF port		–100		dBm
RF to LO	LOIN, LOIP terminated in 50 Ω		–95		dBc
I/Q Magnitude Imbalance			0.05		dB
I/Q Phase Imbalance			0.2		Degrees
LO to I/Q	RFIN, RFIP terminated in 50 Ω , 1xLO appearing at the BB port		–39		dBm
Noise Figure			12.0		dB
Noise Figure under Blocking Conditions	With a –5 dBm interferer 5 MHz away		14.4		dB

Parameter	Condition	Min	Typ	Max	Unit
DYNAMIC PERFORMANCE at RF = 450 MHz					
Conversion Gain			4.4		dB
Input P1dB (IP1dB)			12.7		dBm
Second-Order Input Intercept (IIP2)	–5 dBm each input tone		69.2		dBm
Third-Order Input Intercept (IIP3)	–5 dBm each input tone		32.8		dBm
LO to RF	RFIN, RFIP terminated in 50 Ω , 1xLO appearing at the RF port		–87		dBm
RF to LO	LOIN, LOIP terminated in 50 Ω		–90		dBc
I/Q Magnitude Imbalance			0.05		dB
I/Q Phase Imbalance			0.6		Degrees
LO to I/Q	RFIN, RFIP terminated in 50 Ω , 1xLO appearing at the BB port		–38		dBm
Noise Figure			13.2		dB
DYNAMIC PERFORMANCE at RF = 900 MHz					
Conversion Gain			4.3		dB
Input P1dB (IP1dB)			12.8		dBm
Second-Order Input Intercept (IIP2)	–5 dBm each input tone		61.7		dBm
Third-Order Input Intercept (IIP3)	–5 dBm each input tone		31.2		dBm
LO to RF	RFIN, RFIP terminated in 50 Ω , 1xLO appearing at the RF port		–79		dBm
RF to LO	LOIN, LOIP terminated in 50 Ω		–88		dBc
I/Q Magnitude Imbalance			0.05		dB
I/Q Phase Imbalance			0.2		Degrees
LO to I/Q	RFIN, RFIP terminated in 50 Ω , 1xLO appearing at the BB port		–41		dBm
Noise Figure			14.7		dB
Noise Figure under Blocking Conditions	With a –5 dBm interferer 5 MHz away		15.8		dB
DYNAMIC PERFORMANCE at RF = 1900 MHz					
Conversion Gain			3.8		dB
Input P1dB (IP1dB)			12.8		dBm
Second-Order Input Intercept (IIP2)	–5 dBm each input tone		59.8		dBm
Third-Order Input Intercept (IIP3)	–5 dBm each input tone		27.4		dBm
LO to RF	RFIN, RFIP terminated in 50 Ω , 1xLO appearing at the RF port		–75		dBm
RF to LO	LOIN, LOIP terminated in 50 Ω		–70		dBc
I/Q Magnitude Imbalance			0.05		dB
I/Q Phase Imbalance			0.3		Degrees
LO to I/Q	RFIN, RFIP terminated in 50 Ω , 1xLO appearing at the BB port		–43		dBm
Noise Figure			16.5		dB
Noise Figure under Blocking Conditions	With a –5 dBm interferer 5 MHz away		18.7		dB

¹ See Figure 64 for locations of L1, L2, C10, and C11.

ABSOLUTE MAXIMUM RATINGS

Table 2.

Parameter	Rating
Supply Voltage VPOS1, VPOS2, VPOS3	5.5 V
LO Input Power	13 dBm (re: 50 Ω)
RF/IF Input Power	15 dBm (re: 50 Ω)
Internal Maximum Power Dissipation	1100 mW
θ_{JA}	54°C/W
Maximum Junction Temperature	150°C
Operating Temperature Range	–40°C to +85°C
Storage Temperature Range	–65°C to +125°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

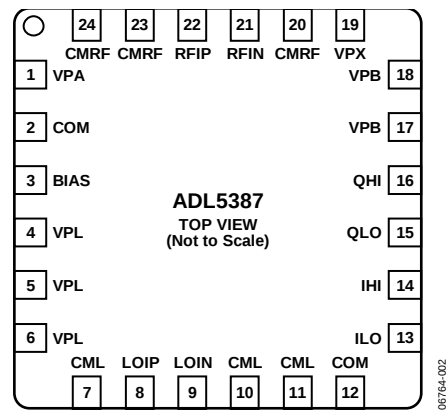


Figure 2. Pin Configuration

Table 3. Pin Function Descriptions

Pin No.	Mnemonic	Description
1, 4 to 6, 17 to 19	VPA, VPL, VPB, VPX	Supply. Positive supply for LO, IF, biasing and baseband sections, respectively. These pins should be decoupled to board ground using appropriate sized capacitors.
2, 7, 10 to 12, 20, 23, 24	COM, CML, CMRF	Ground. Connect to a low impedance ground plane.
3	BIAS	Bias Control. A resistor can be connected between BIAS and COM to reduce the mixer core current. The default setting for this pin is open.
8, 9	LOIP, LOIN	Local Oscillator. External LO input is at 2xLO frequency. A single-ended LO at 0 dBm can be applied through a 1000 pF capacitor to LOIP. LOIN should be ac-grounded, also using a 1000 pF. These inputs can also be driven differentially through a balun (recommended balun is M/A-COM ETC1-1-13).
13 to 16	ILO, IHI, QLO, QHI	I-Channel and Q-Channel Mixer Baseband Outputs. These outputs have a 50 Ω differential output impedance (25 Ω per pin). The bias level on these pins is equal to VPOS – 2.8 V. Each output pair can swing 2 V p-p (differential) into a load of 200 Ω . Output 3 dB bandwidth is 240 MHz.
21, 22	RFIN, RFIP	RF Input. A single-ended 50 Ω signal can be applied to the RF inputs through a 1:1 balun (recommended balun is M/A-COM ETC1-1-13). Ground-referenced inductors must also be connected to RFIP and RFIN (recommended values = 120 nH).
	EP	Exposed Paddle. Connect to a low impedance ground plane.

TYPICAL PERFORMANCE CHARACTERISTICS

$V_S = 5\text{ V}$, $T_A = 25^\circ\text{C}$, LO drive level = 0 dBm, $R_{BIAS} = \text{open}$, unless otherwise noted.

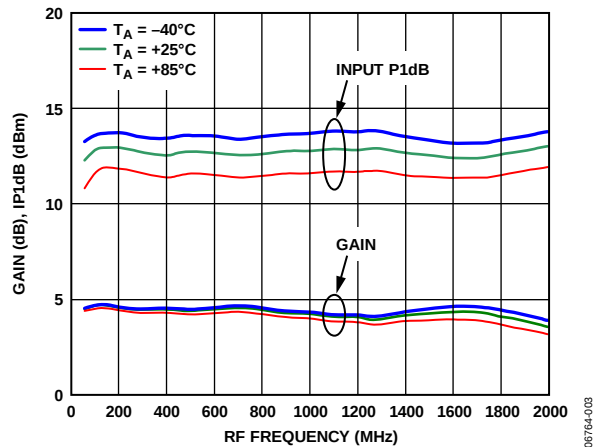


Figure 3. Conversion Gain and Input 1 dB Compression Point (IP1dB) vs. RF Frequency

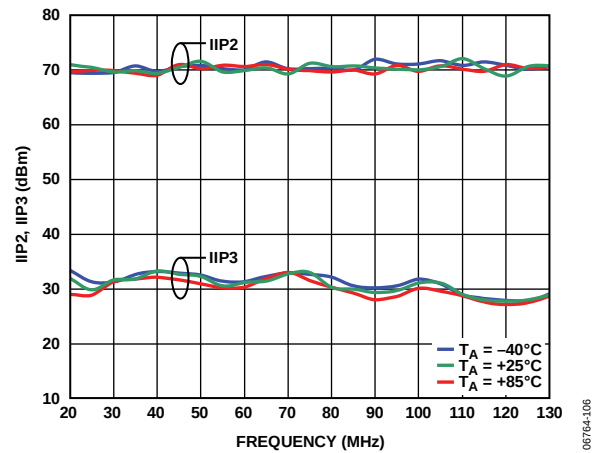


Figure 6. Input Third-Order Intercept (IIP3) and Input Second-Order Intercept Point (IIP2) vs. RF Frequency (Low Frequency Range)

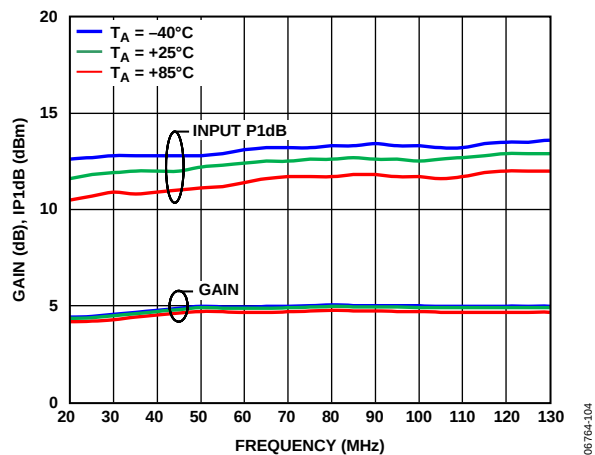


Figure 4. Conversion Gain and Input 1 dB Compression Point (IP1dB) vs. RF Frequency (Low Frequency Range)

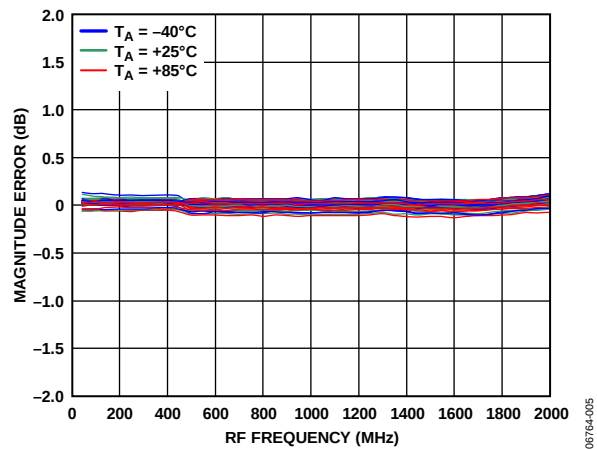


Figure 7. I/Q Gain Mismatch vs. RF Frequency

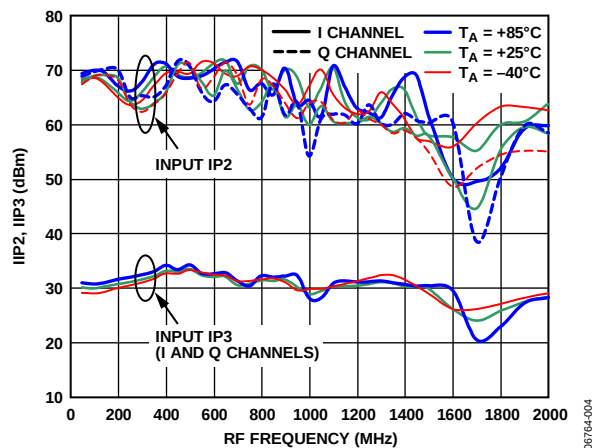


Figure 5. Input Third-Order Intercept (IIP3) and Input Second-Order Intercept Point (IIP2) vs. RF Frequency

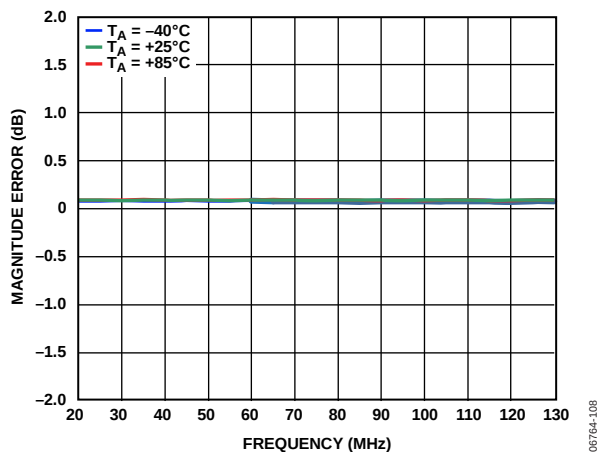


Figure 8. I/Q Gain Mismatch vs. RF Frequency (Low Frequency Range)

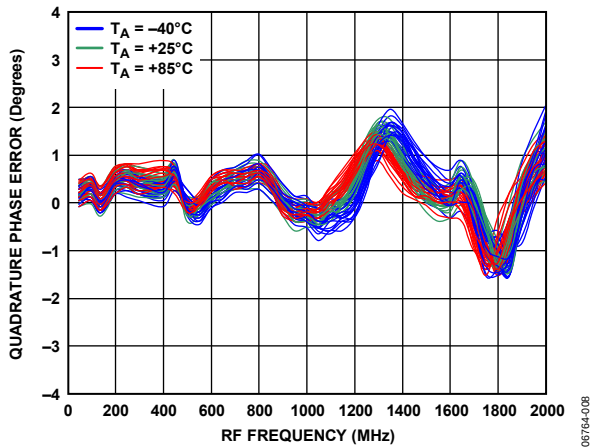


Figure 9. I/Q Quadrature Phase Error vs. RF Frequency

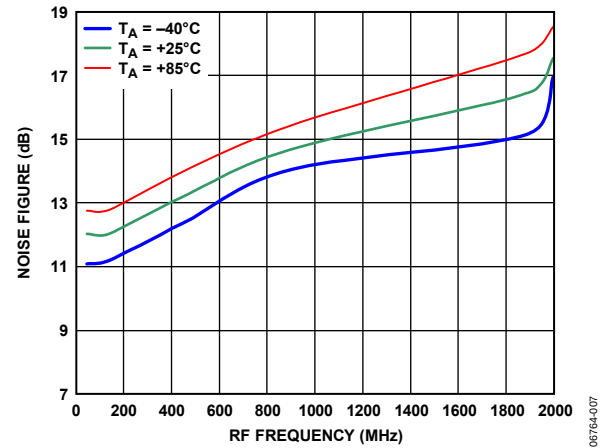


Figure 12. Noise Figure vs. RF Frequency

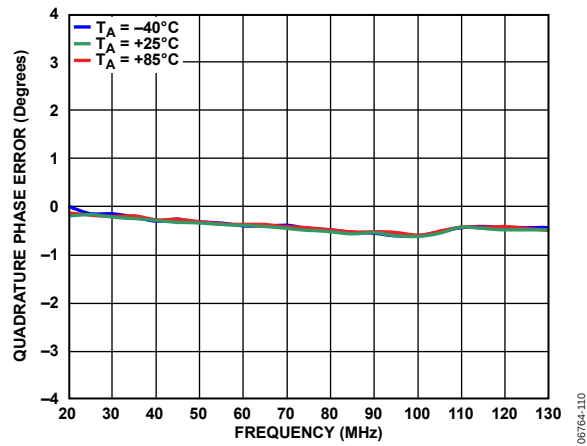


Figure 10. I/Q Quadrature Phase Error vs. RF Frequency (Low Frequency Range)

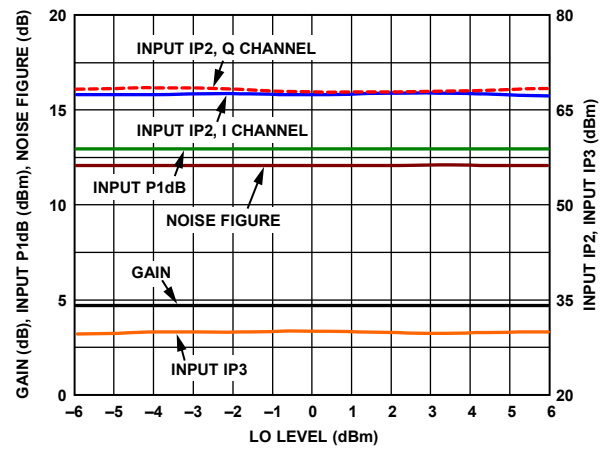
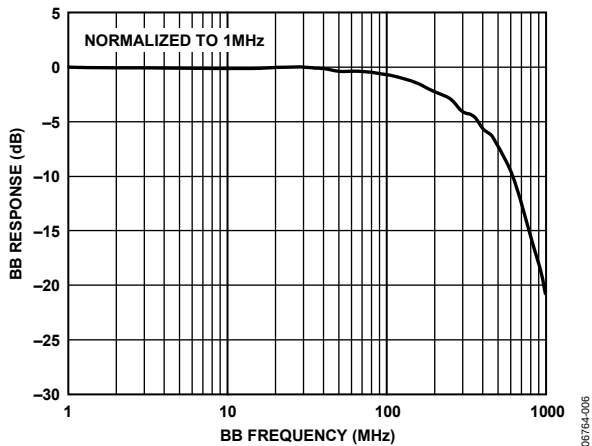
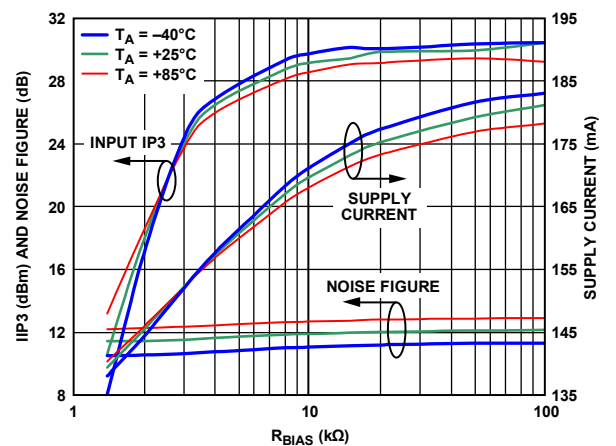
Figure 13. Conversion Gain, Noise Figure, IIP3, IIP2, and IP1dB vs. LO Level, $f_{RF} = 140$ MHz

Figure 11. Normalized I/Q Baseband Frequency Response

Figure 14. Noise Figure, IIP3, and Supply Current vs. R_{BIAS} , $f_{RF} = 140$ MHz

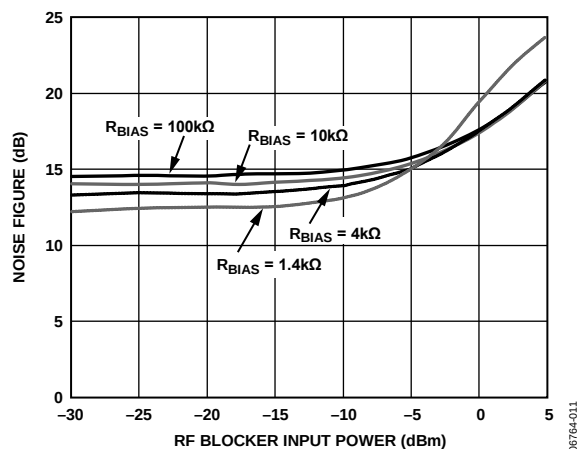


Figure 15. Noise Figure vs. Input Blocker Level, $f_{RF} = 900$ MHz (RF Blocker 5 MHz Offset)

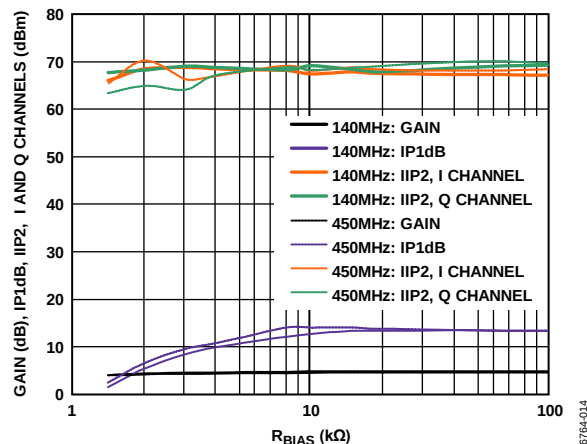


Figure 18. Conversion Gain, IP1dB, IIP2, I and IIP2 Q Channel vs. R_{BIAS}

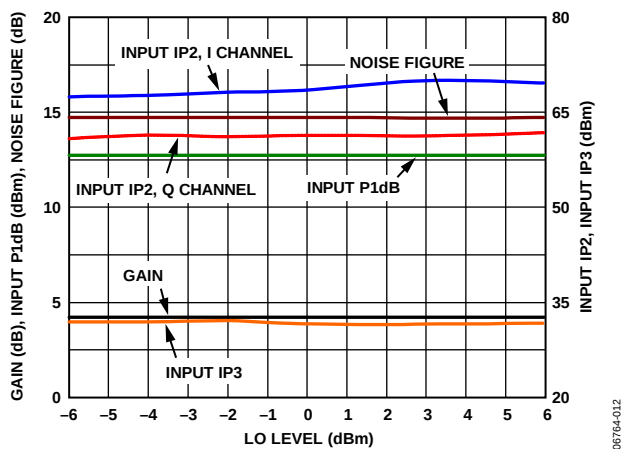


Figure 16. Conversion Gain, Noise Figure, IIP3, IIP2, and IP1dB vs. LO Level, $f_{RF} = 900$ MHz

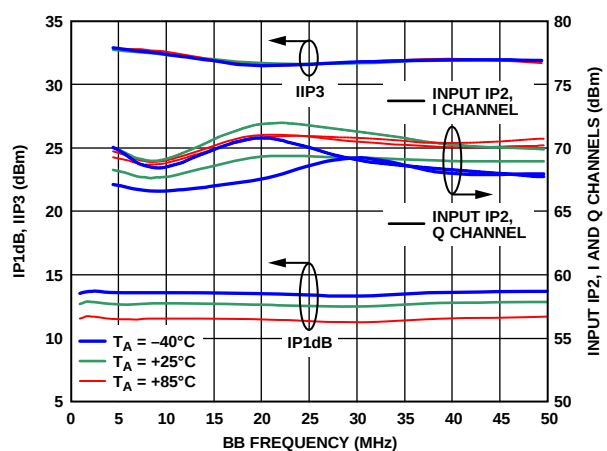


Figure 19. IIP3, IIP2, IP1dB vs. Baseband Frequency

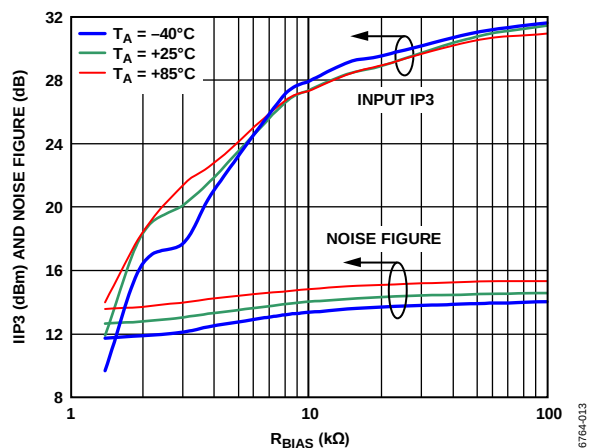


Figure 17. IIP3 and Noise Figure vs. R_{BIAS} , $f_{RF} = 900$ MHz

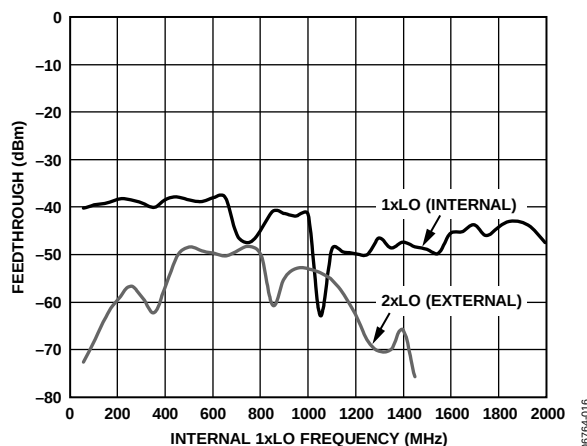


Figure 20. LO-to-BB Feedthrough vs. 1xLO Frequency (Internal LO Frequency)

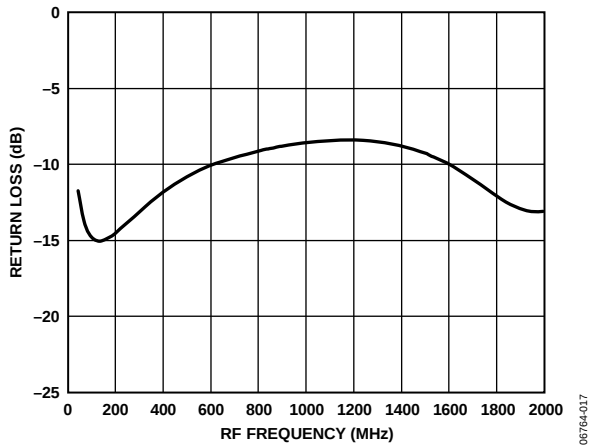


Figure 21. RF Port Return Loss vs. RF Frequency, Measured on Characterization Board through ETC1-1-13 Balun with 120 nH Bias Inductors

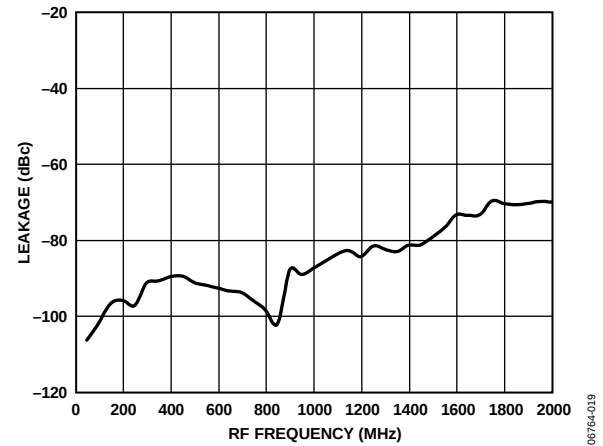


Figure 23. RF-to-LO Leakage vs. RF Frequency

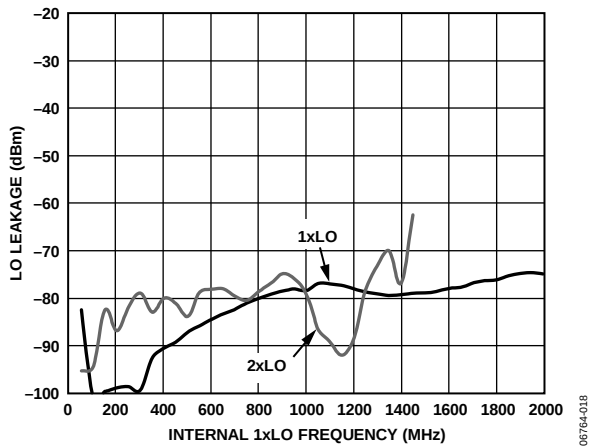


Figure 22. LO-to-RF Leakage vs. Internal 1xLO Frequency

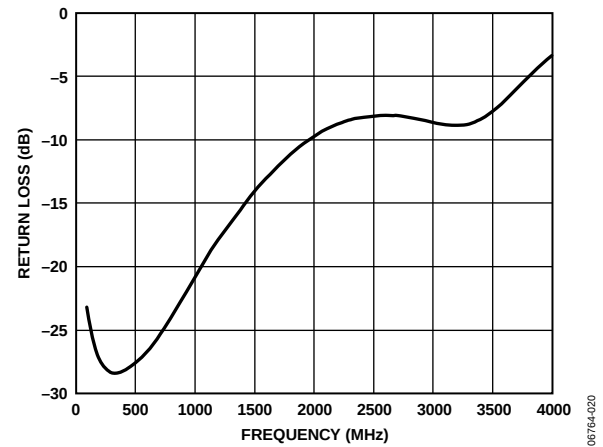


Figure 24. Single-Ended LO Port Return Loss vs. LO Frequency, LOIN AC-Coupled to Ground

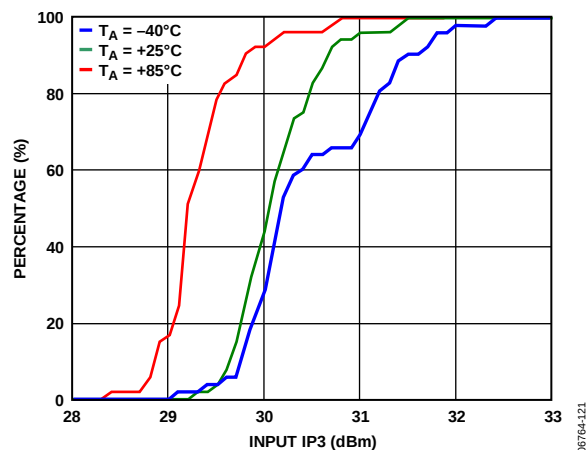
DISTRIBUTIONS FOR $f_{RF} = 140 \text{ MHz}$ 

Figure 25. IIP3 Distributions

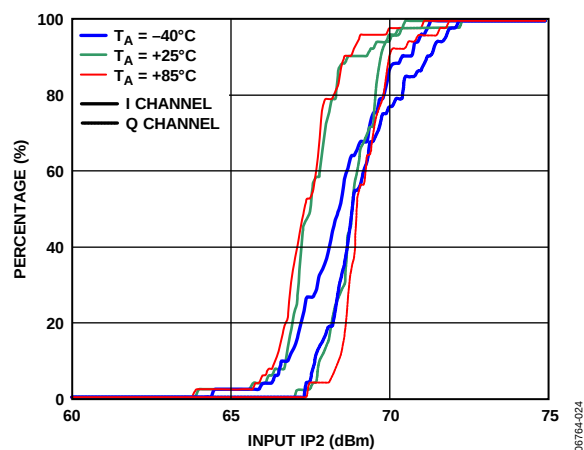


Figure 28. IIP2 Distributions for I Channel and Q Channel

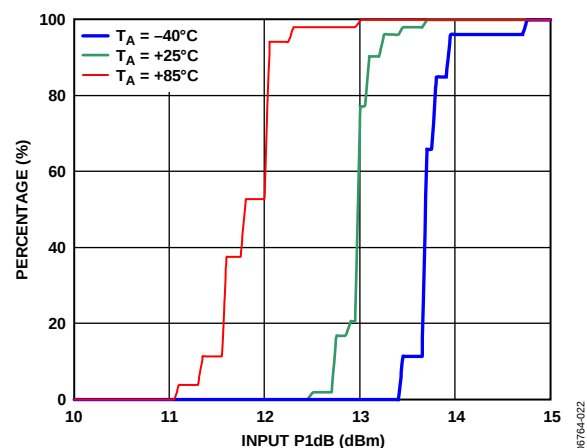


Figure 26. IP1dB Distributions

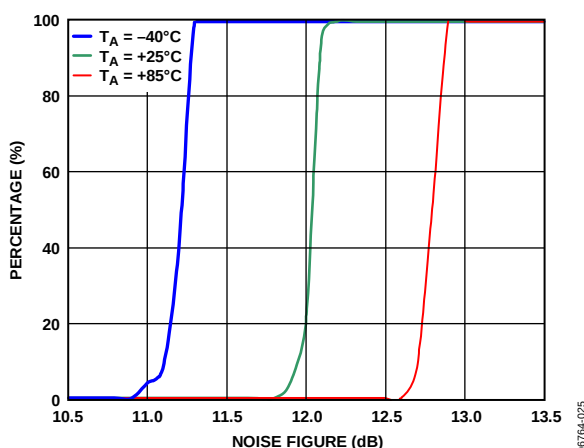


Figure 29. Noise Figure Distributions

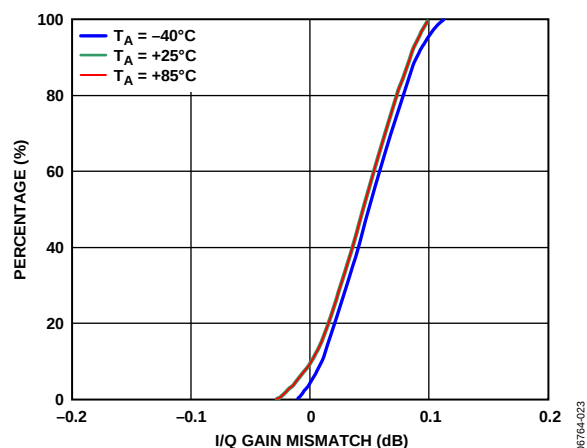


Figure 27. I/Q Gain Mismatch Distributions

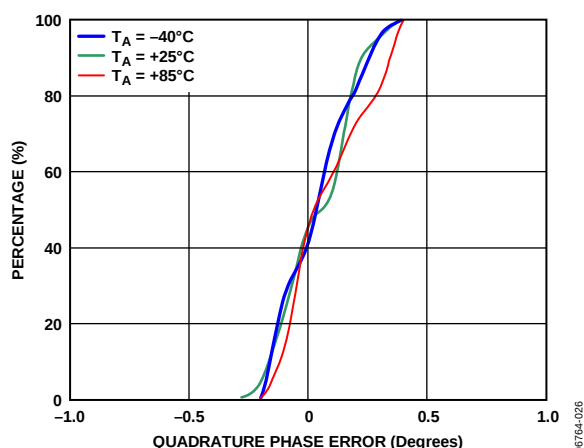


Figure 30. I/Q Quadrature Error Distributions

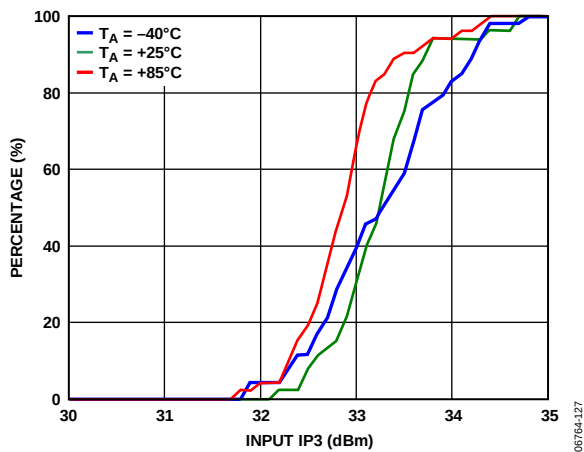
DISTRIBUTIONS FOR $f_{RF} = 450 \text{ MHz}$ 

Figure 31. IIP3 Distributions

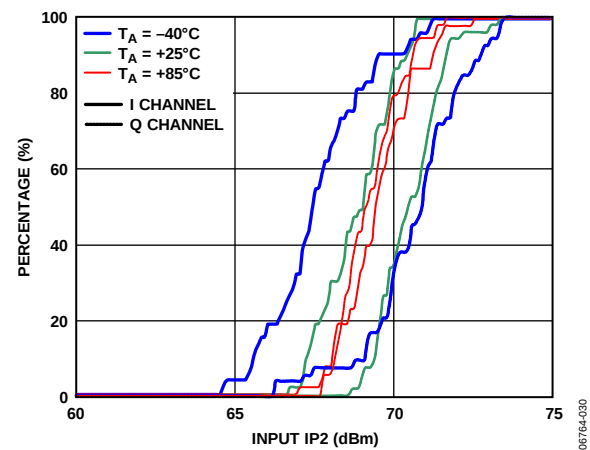


Figure 34. IIP2 Distributions for I Channel and Q Channel

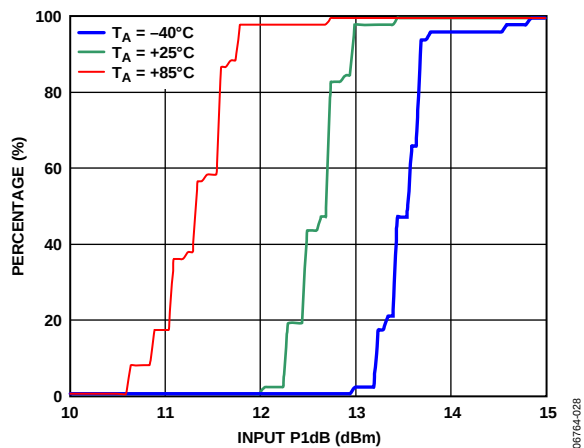


Figure 32. IP1dB Distributions

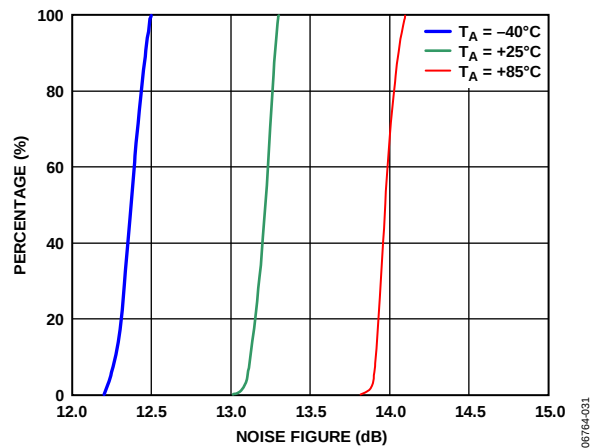


Figure 35. Noise Figure Distributions

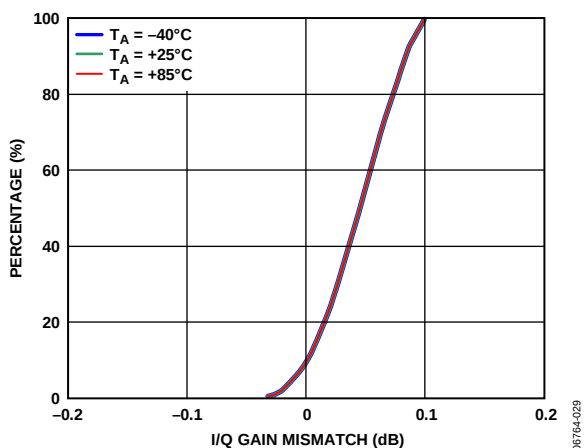


Figure 33. I/Q Gain Mismatch Distributions

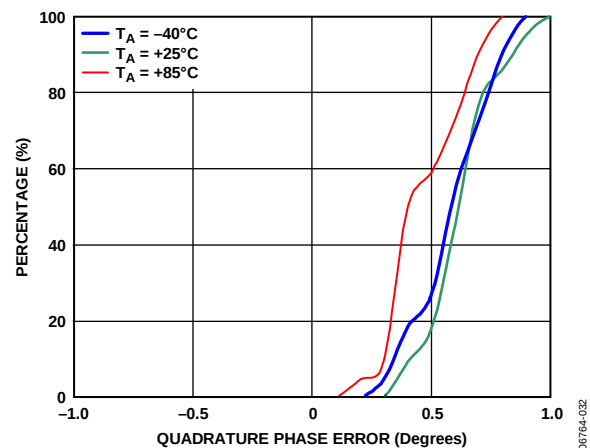


Figure 36. I/Q Quadrature Error Distributions

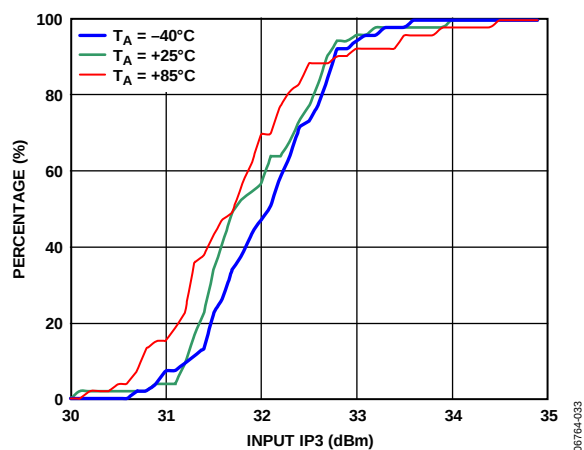
DISTRIBUTIONS FOR $f_{RF} = 900 \text{ MHz}$ 

Figure 37. IIP3 Distributions

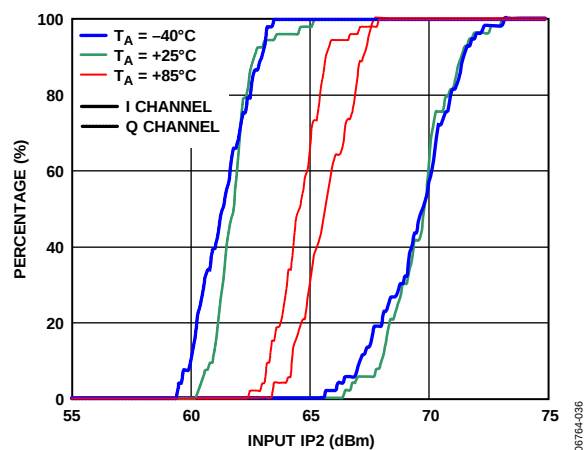


Figure 40. IIP2 Distributions for I Channel and Q Channel

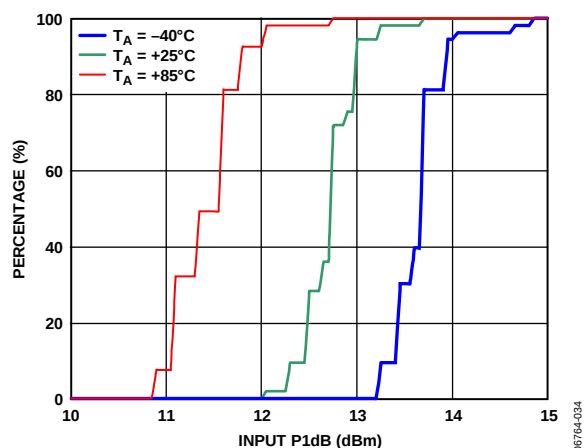


Figure 38. IP1dB Distributions

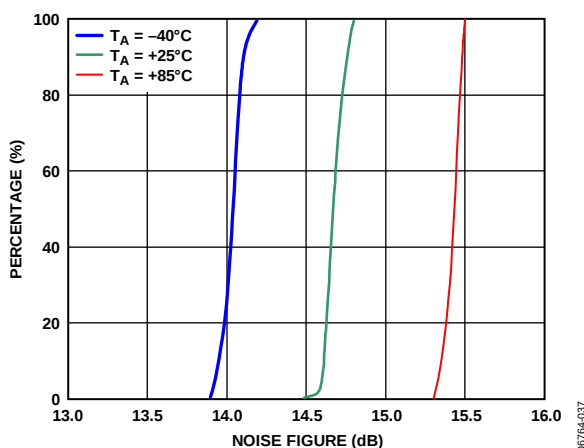


Figure 41. Noise Figure Distributions

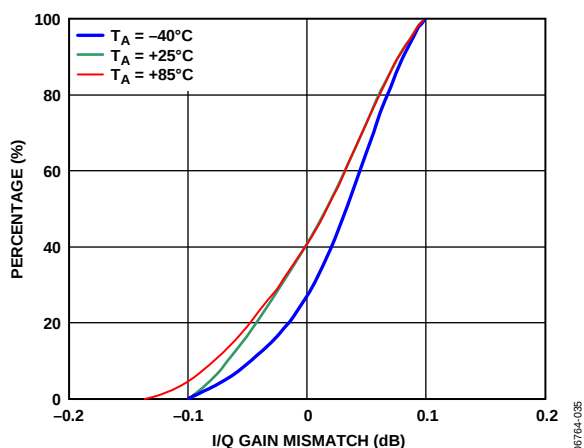


Figure 39. I/Q Gain Mismatch Distributions

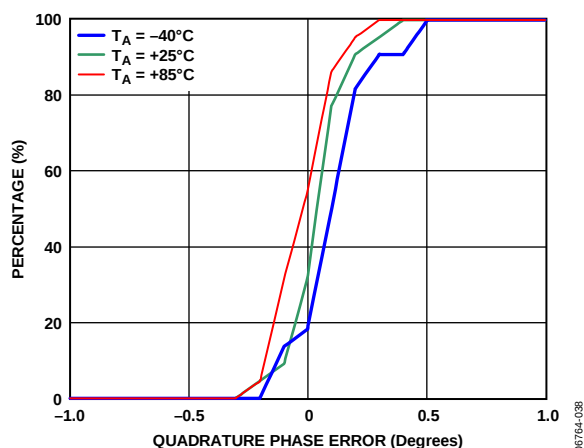


Figure 42. I/Q Quadrature Error Distributions

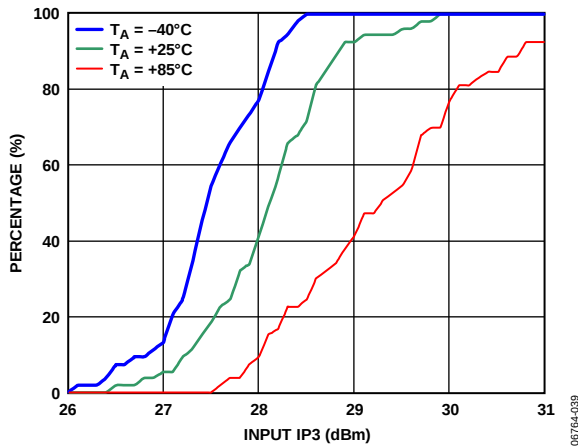
DISTRIBUTIONS FOR $f_{RF} = 1900 \text{ MHz}$ 

Figure 43. IIP3 Distributions

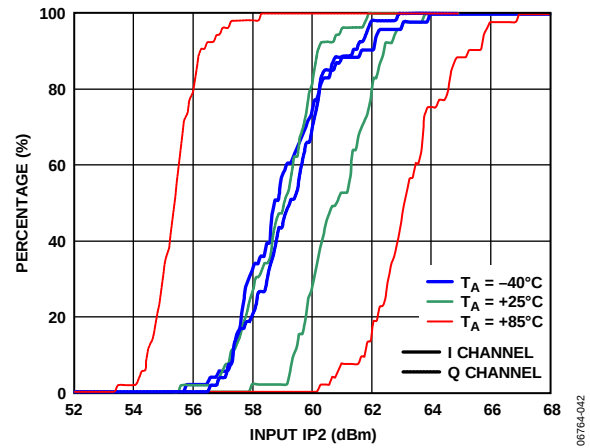


Figure 46. IIP2 Distributions for I Channel and Q Channel

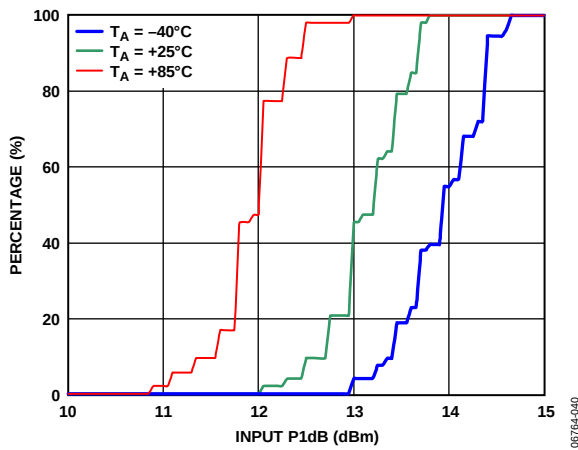


Figure 44. IP1dB Distributions

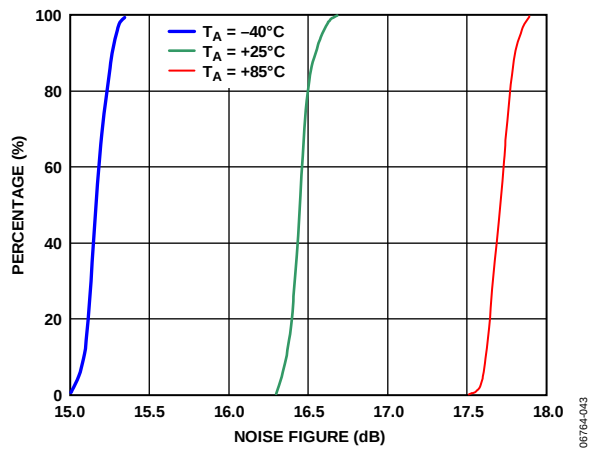


Figure 47. Noise Figure Distributions

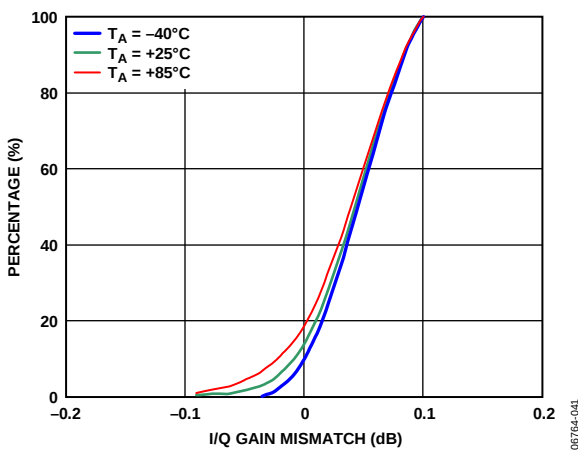


Figure 45. I/Q Gain Mismatch Distributions

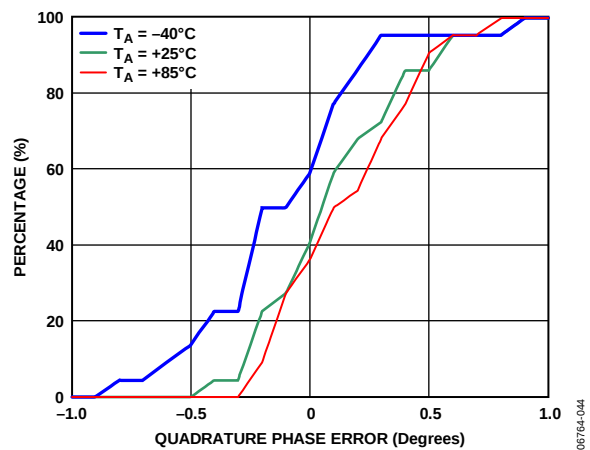


Figure 48. I/Q Quadrature Error Distributions

CIRCUIT DESCRIPTION

The ADL5387 can be divided into five sections: the local oscillator (LO) interface, the RF voltage-to-current (V-to-I) converter, the mixers, the differential emitter follower outputs, and the bias circuit. A detailed block diagram of the device is shown in Figure 49.

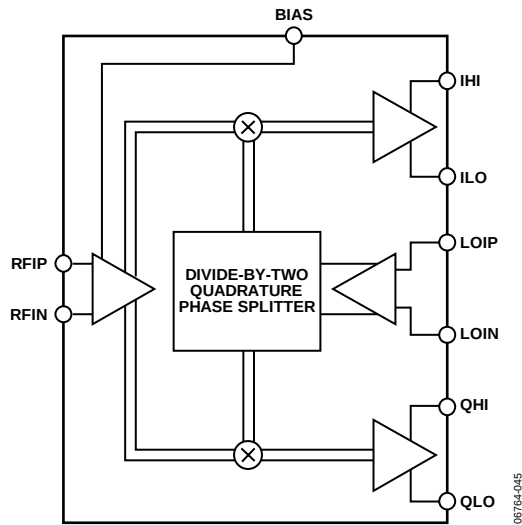


Figure 49. Block Diagram

The LO interface generates two LO signals at 90° of phase difference to drive two mixers in quadrature. RF signals are converted into currents by the V-to-I converters that feed into the two mixers. The differential I and Q outputs of the mixers are buffered via emitter followers. Reference currents to each section are generated by the bias circuit. A detailed description of each section follows.

LO INTERFACE

The LO interface consists of a buffer amplifier followed by a frequency divider that generate two carriers at half the input frequency and in quadrature with each other. Each carrier is then amplified and amplitude-limited to drive the double-balanced mixers.

V-TO-I CONVERTER

The differential RF input signal is applied to a resistively degenerated common base stage, which converts the differential input voltage to output currents. The output currents then modulate the two half-frequency LO carriers in the mixer stage.

MIXERS

The ADL5387 has two double-balanced mixers: one for the in-phase channel (I channel) and one for the quadrature channel (Q channel). These mixers are based on the Gilbert cell design of four cross-connected transistors. The output currents from the two mixers are summed together in the resistive loads that then feed into the subsequent emitter follower buffers.

EMITTER FOLLOWER BUFFERS

The output emitter followers drive the differential I and Q signals off-chip. The output impedance is set by on-chip 25 Ω series resistors that yield a 50 Ω differential output impedance for each baseband port. The fixed output impedance forms a voltage divider with the load impedance that reduces the effective gain. For example, a 500 Ω differential load has 1 dB lower effective gain than a high (10 k Ω) differential load impedance.

BIAS CIRCUIT

A band gap reference circuit generates the proportional-to-absolute temperature (PTAT) as well as temperature-independent reference currents used by different sections. The mixer current can be reduced via an external resistor between the BIAS pin and ground. When the BIAS pin is open, the mixer runs at maximum current and hence the greatest dynamic range. The mixer current can be reduced by placing a resistance to ground; therefore, reducing overall power consumption, noise figure, and IIP3. The effect on each of these parameters is shown in Figure 14, Figure 17, and Figure 18.

APPLICATIONS INFORMATION

BASIC CONNECTIONS

Figure 51 shows the basic connections schematic for the [ADL5387](#).

POWER SUPPLY

The nominal voltage supply for the [ADL5387](#) is 5 V and is applied to the VPA, VPB, VPL, and VPX pins. Ground should be connected to the COM, CML, and CMRF pins. Each of the supply pins should be decoupled using two capacitors; recommended capacitor values are 100 pF and 0.1 μ F.

LOCAL OSCILLATOR (LO) INPUT

The LO port is driven in a single-ended manner. The LO signal must be ac-coupled via a 1000 pF capacitor directly into LOIP, and LOIN is ac-coupled to ground also using a 1000 pF capacitor. The LO port is designed for a broadband 50 Ω match and therefore exhibits excellent return loss from 60 MHz to 4 GHz. The LO return loss can be seen in Figure 24. Figure 50 shows the LO input configuration.

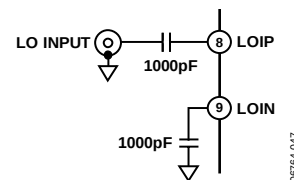


Figure 50. Single-Ended LO Drive

The recommended LO drive level is between -6 dBm and $+6$ dBm. For operation below 50 MHz, a minimum LO drive level of 0 dBm should be used. The LO frequency at the input to the device should be twice that of the desired LO frequency at the mixer core. The applied LO frequency range is between 60 MHz and 4 GHz.

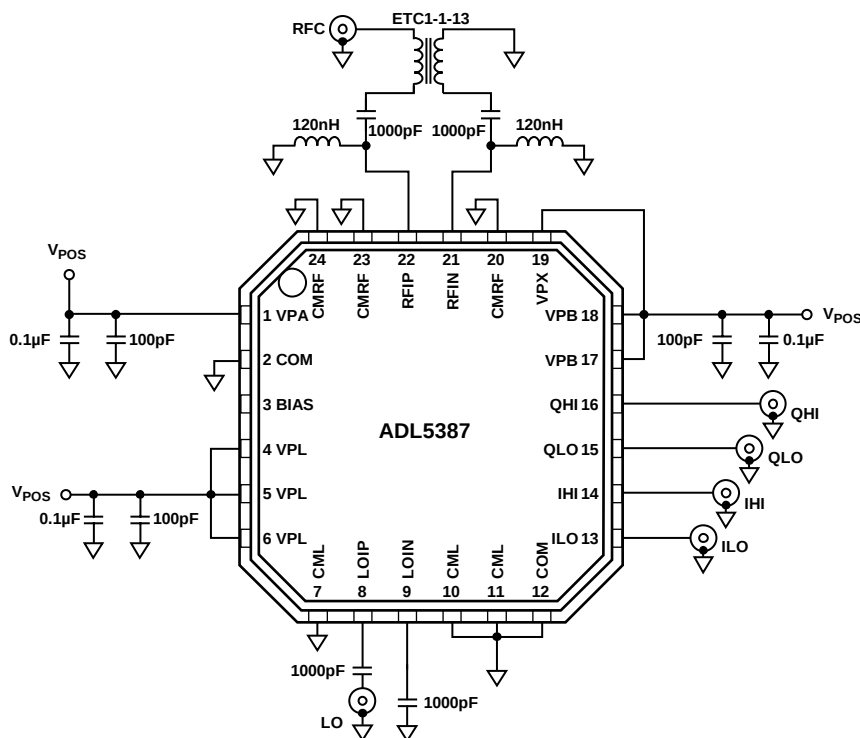


Figure 51. Basic Connections Schematic for [ADL5387](#)

RF INPUT

The RF inputs have a differential input impedance of approximately $50\ \Omega$. For optimum performance, the RF port should be driven differentially through a balun. The recommended balun is M/A-COM ETC1-1-13. The RF inputs to the device should be ac-coupled with 1000 pF capacitors. Ground-referenced choke inductors must also be connected to RFIP and RFIN (recommended value = 120 nH, Coilcraft 0402CS-R12XJL) for appropriate biasing. Several important aspects must be taken into account when selecting an appropriate choke inductor for this application. First, the inductor must be able to handle the approximately 40 mA of standing dc current being delivered from each of the RF input pins (RFIP, RFIN). (The suggested 0402 inductor has a 50 mA current rating). The purpose of the choke inductors is to provide a very low resistance dc path to ground and high ac impedance at the RF frequency so as not to affect the RF input impedance. A choke inductor that has a self-resonant frequency greater than the RF input frequency ensures that the choke is still looking inductive and therefore has a more predictable ac impedance ($j\omega L$) at the RF frequency. Figure 52 shows the RF input configuration.

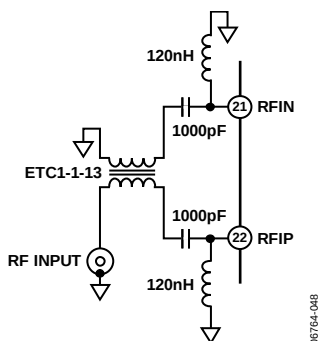


Figure 52. RF Input

The differential RF port return loss has been characterized as shown in Figure 53.

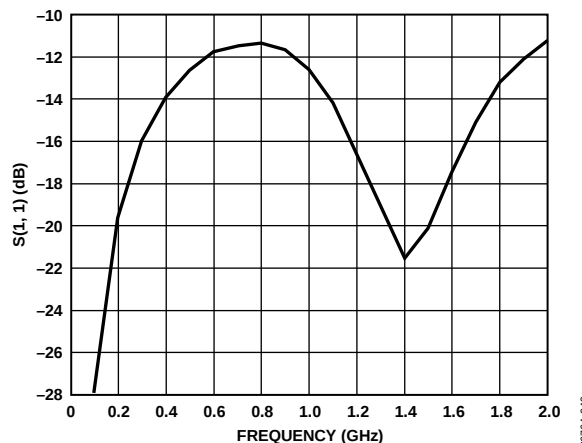


Figure 53. Differential RF Port Return Loss

BASEBAND OUTPUTS

The baseband outputs QHI, QLO, IHI, and ILO are fixed impedance ports. Each baseband pair has a $50\ \Omega$ differential output impedance. The outputs can be presented with differential loads as low as $200\ \Omega$ (with some degradation in linearity and gain) or high impedance differential loads ($500\ \Omega$ or greater impedance yields the same excellent linearity) that is typical of an ADC. The TCM9-1 9:1 balun converts the differential IF output to single-ended. When loaded with $50\ \Omega$, this balun presents a $450\ \Omega$ load to the device. The typical maximum linear voltage swing for these outputs is 2 V p-p differential. The bias level on these pins is equal to $V_{POS} - 2.8\text{ V}$. The output 3 dB bandwidth is 240 MHz. Figure 54 shows the baseband output configuration.

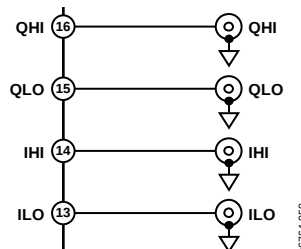


Figure 54. Baseband Output Configuration

ERROR VECTOR MAGNITUDE (EVM) PERFORMANCE

EVM is a measure used to quantify the performance of a digital radio transmitter or receiver. A signal received by a receiver would have all constellation points at the ideal locations; however, various imperfections in the implementation (such as carrier leakage, phase noise, and quadrature error) cause the actual constellation points to deviate from the ideal locations.

The ADL5387 shows excellent EVM performance for various modulation schemes. Figure 55 shows typical EVM performance over input power range for a point-to-point application with 16 QAM modulation schemes and zero-IF baseband. The differential dc offsets on the ADL5387 are in the order of a few mV. However, ac coupling the baseband outputs with 10 μ F capacitors helps to eliminate dc offsets and enhances EVM performance. With a 10 MHz BW signal, 10 μ F ac coupling capacitors with the 500 Ω differential load results in a high-pass corner frequency of ~ 64 Hz which absorbs an insignificant amount of modulated signal energy from the baseband signal. By using ac coupling capacitors at the baseband outputs, the dc offset effects, which can limit dynamic range at low input power levels, can be eliminated.

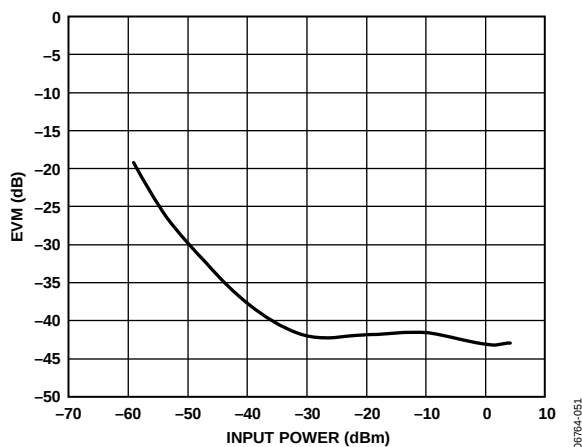


Figure 55. RF = 140 MHz, IF = 0 Hz, EVM vs. Input Power for a 16 QAM 10 Msym/s Signal (AC-Coupled Baseband Outputs)

Figure 56 shows the EVM performance of the ADL5387 when ac-coupled, with an IEEE 802.16e WiMAX signal.

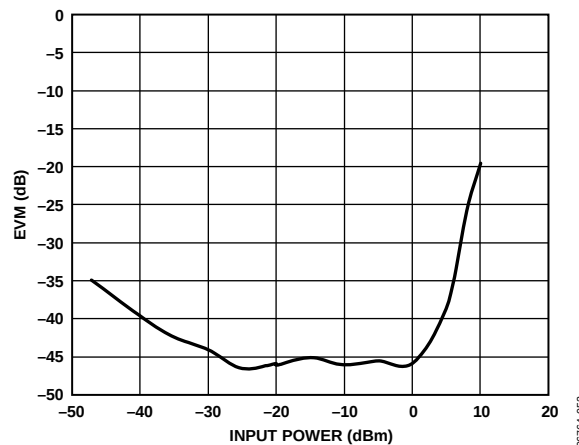


Figure 56. RF = 750 MHz, IF = 0 Hz, EVM vs. Input Power for a 16 QAM 10 MHz Bandwidth Mobile WiMAX Signal (AC-Coupled Baseband Outputs)

Figure 57 exhibits the zero IF EVM performance of a WCDMA signal over a wide RF input power range.

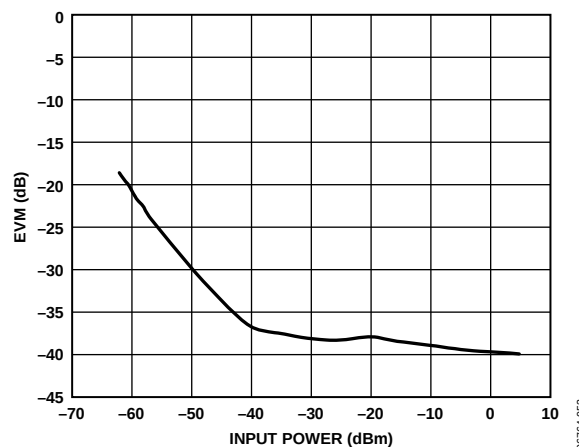


Figure 57. RF = 1950 MHz, IF = 0 Hz, EVM vs. Input Power for a WCDMA (AC-Coupled Baseband Outputs)

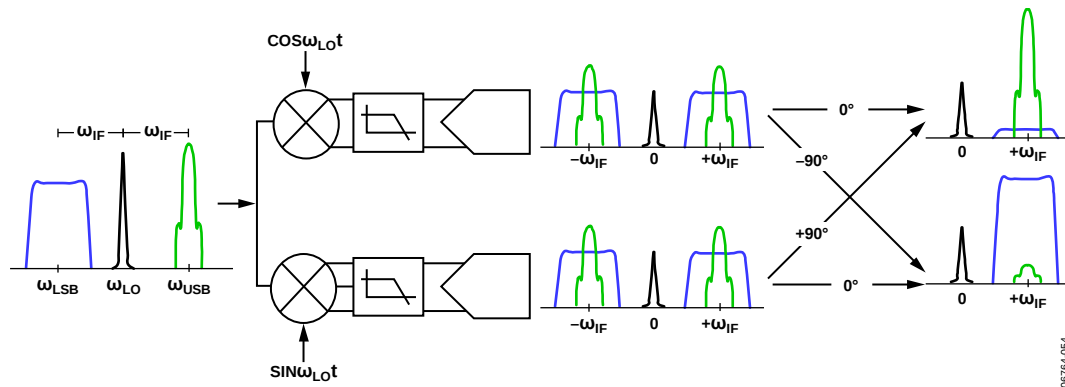


Figure 58. Illustration of the Image Problem

LOW IF IMAGE REJECTION

The image rejection ratio is the ratio of the intermediate frequency (IF) signal level produced by the desired input frequency to that produced by the image frequency. The image rejection ratio is expressed in decibels. Appropriate image rejection is critical because the image power can be much higher than that of the desired signal, thereby plaguing the down conversion process. Figure 58 illustrates the image problem. If the upper sideband (lower sideband) is the desired band, a 90° shift to the Q channel (I channel) cancels the image at the lower sideband (upper sideband).

Figure 59 shows the excellent image rejection capabilities of the ADL5387 for low IF applications, such as CDMA2000. The ADL5387 exhibits image rejection greater than 45 dB over the broad frequency range for an IF = 1.23 MHz.

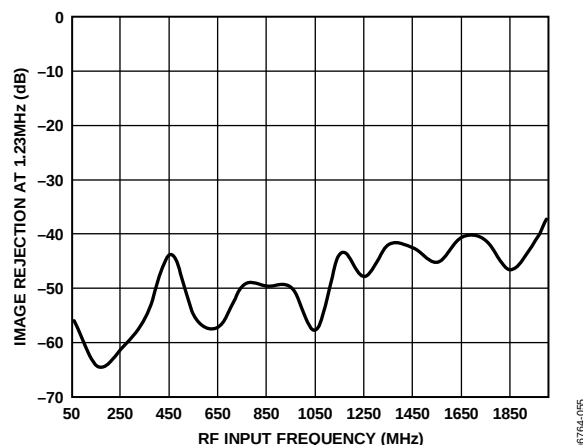


Figure 59. Image Rejection vs. RF Input Frequency for a CDMA2000 Signal, IF = 1.23 MHz

EXAMPLE BASEBAND INTERFACE

In most direct conversion receiver designs, it is desirable to select a wanted carrier within a specified band. The desired channel can be demodulated by tuning the LO to the appropriate carrier frequency. If the desired RF band contains multiple carriers of interest, the adjacent carriers would also be down converted to a lower IF frequency. These adjacent carriers can be problematic if they are large relative to the wanted carrier as they can overdrive the baseband signal detection circuitry. As a result, it is often necessary to insert a filter to provide sufficient rejection of the adjacent carriers.

It is necessary to consider the overall source and load impedance presented by the ADL5387 and ADC input to design the filter network. The differential baseband output impedance of the ADL5387 is 50 Ω . The ADL5387 is designed to drive a high impedance ADC input. It may be desirable to terminate the ADC input down to lower impedance by using a terminating resistor, such as 500 Ω . The terminating resistor helps to better define the input impedance at the ADC input. The order and type of filter network depends on the desired high frequency rejection required, pass-band ripple, and group delay. Filter design tables provide outlines for various filter types and orders, illustrating the normalized inductor and capacitor values for a 1 Hz cutoff frequency and 1 Ω load. After scaling the normalized prototype element values by the actual desired cut-off frequency and load impedance, the series reactance elements are halved to realize the final balanced filter network component values.

As an example, a second-order, Butterworth, low-pass filter design is shown in Figure 60 where the differential load impedance is $500\ \Omega$, and the source impedance of the ADL5387 is $50\ \Omega$. The normalized series inductor value for the 10-to-1, load-to-source impedance ratio is $0.074\ \text{H}$, and the normalized shunt capacitor is $14.814\ \text{F}$. For a $10.9\ \text{MHz}$ cutoff frequency, the single-ended equivalent circuit consists of a $0.54\ \mu\text{H}$ series inductor followed by a $433\ \text{pF}$ shunt capacitor.

The balanced configuration is realized as the $0.54\ \mu\text{H}$ inductor is split in half to realize the network shown in Figure 60.

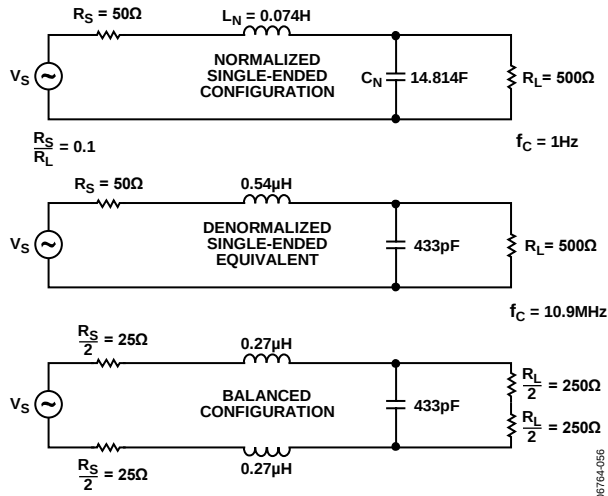


Figure 60. Second-Order, Butterworth, Low-Pass Filter Design Example

A complete design example is shown in Figure 63. A sixth-order Butterworth differential filter having a $1.9\ \text{MHz}$ corner frequency interfaces the output of the ADL5387 to that of an ADC input. The $500\ \Omega$ load resistor defines the input impedance of the ADC. The filter adheres to typical direct conversion WCDMA applications, where $1.92\ \text{MHz}$ away from the carrier IF frequency, $1\ \text{dB}$ of rejection is desired and $2.7\ \text{MHz}$ away $10\ \text{dB}$ of rejection is desired.

Figure 61 and Figure 62 show the measured frequency response and group delay of the filter.

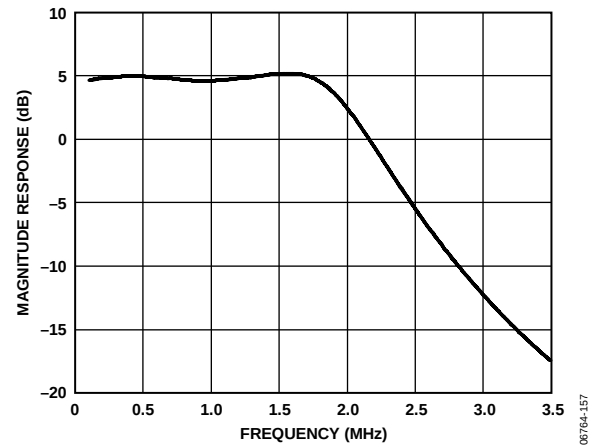


Figure 61. Baseband Filter Response

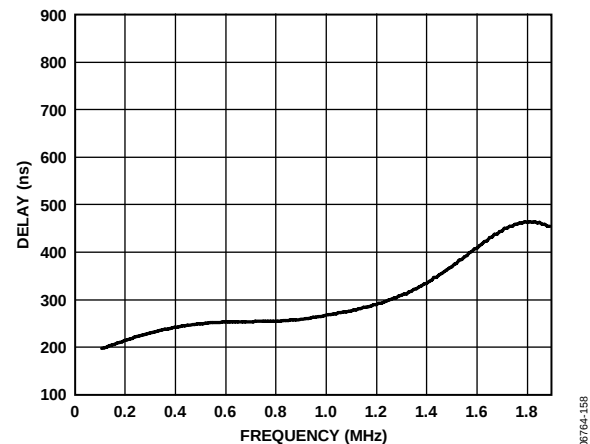


Figure 62. Baseband Filter Group Delay



Rev. B | Page 21 of 28

CHARACTERIZATION SETUPS

Figure 64 to Figure 66 show the general characterization bench setups used extensively for the ADL5387. The setup shown in Figure 66 was used to do the bulk of the testing and used sinusoidal signals on both the LO and RF inputs. An automated Agilent-VEE program was used to control the equipment over the IEEE bus. This setup was used to measure gain, IP1dB, IIP2, IIP3, I/Q gain match, and quadrature error. The ADL5387 characterization board had a 9-to-1 impedance transformer on each of the differential baseband ports to do the differential-to-single-ended conversion.

The two setups shown in Figure 64 and Figure 65 were used for making NF measurements. Figure 64 shows the setup for measuring NF with no blocker signal applied while Figure 65 was used to measure NF in the presence of a blocker. For both setups, the noise was measured at a baseband frequency of

10 MHz. For the case where a blocker was applied, the output blocker was at 15 MHz baseband frequency. Note that great care must be taken when measuring NF in the presence of a blocker. The RF blocker generator must be filtered to prevent its noise (which increases with increasing generator output power) from swamping the noise contribution of the ADL5387. At least 30 dB of attenuation at the RF and image frequencies is desired. For example, with a 2xLO of 1848 MHz applied to the ADL5387, the internal 1xLO is 924 MHz. To obtain a 15 MHz output blocker signal, the RF blocker generator is set to 939 MHz and the filters tuned such that there is at least 30 dB of attenuation from the generator at both the desired RF frequency (934 MHz) and the image RF frequency (914 MHz). Finally, the blocker must be removed from the output (by the 10 MHz low-pass filter) to prevent the blocker from swamping the analyzer.

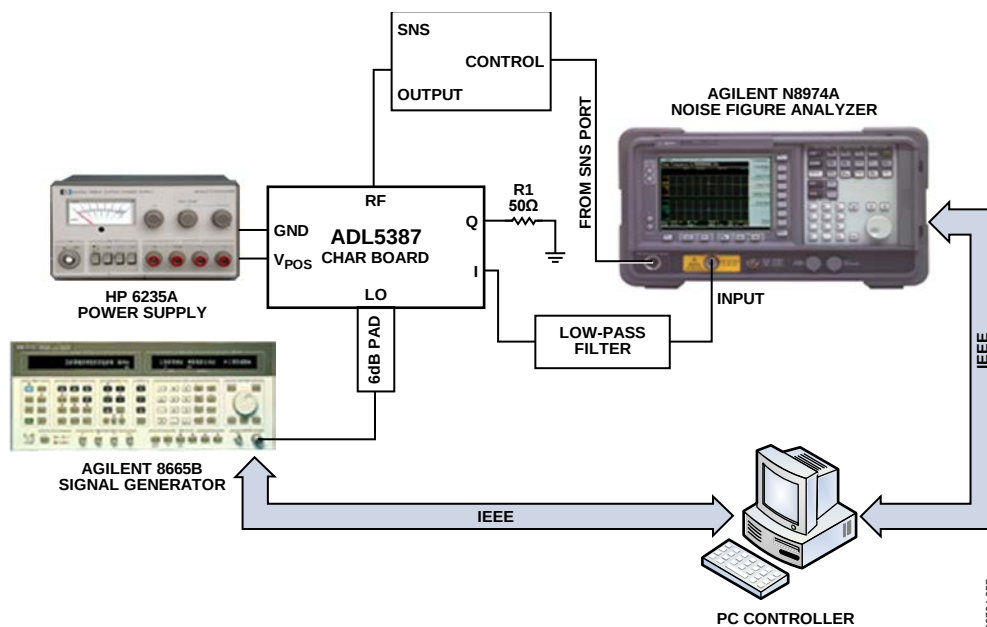


Figure 64. General Noise Figure Measurement Setup

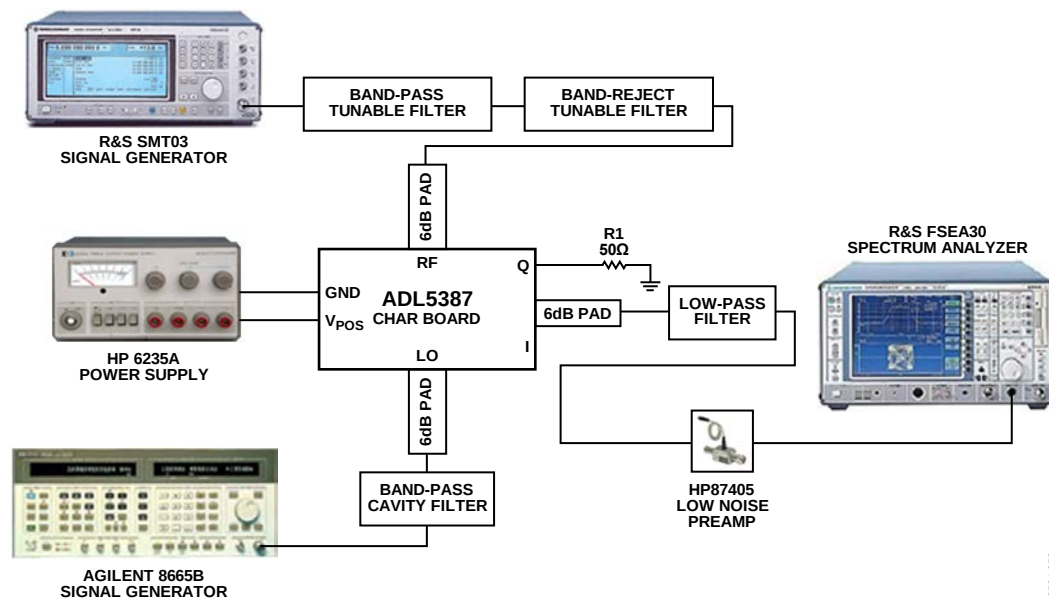


Figure 65. Measurement Setup for Noise Figure in the Presence of a Blocker

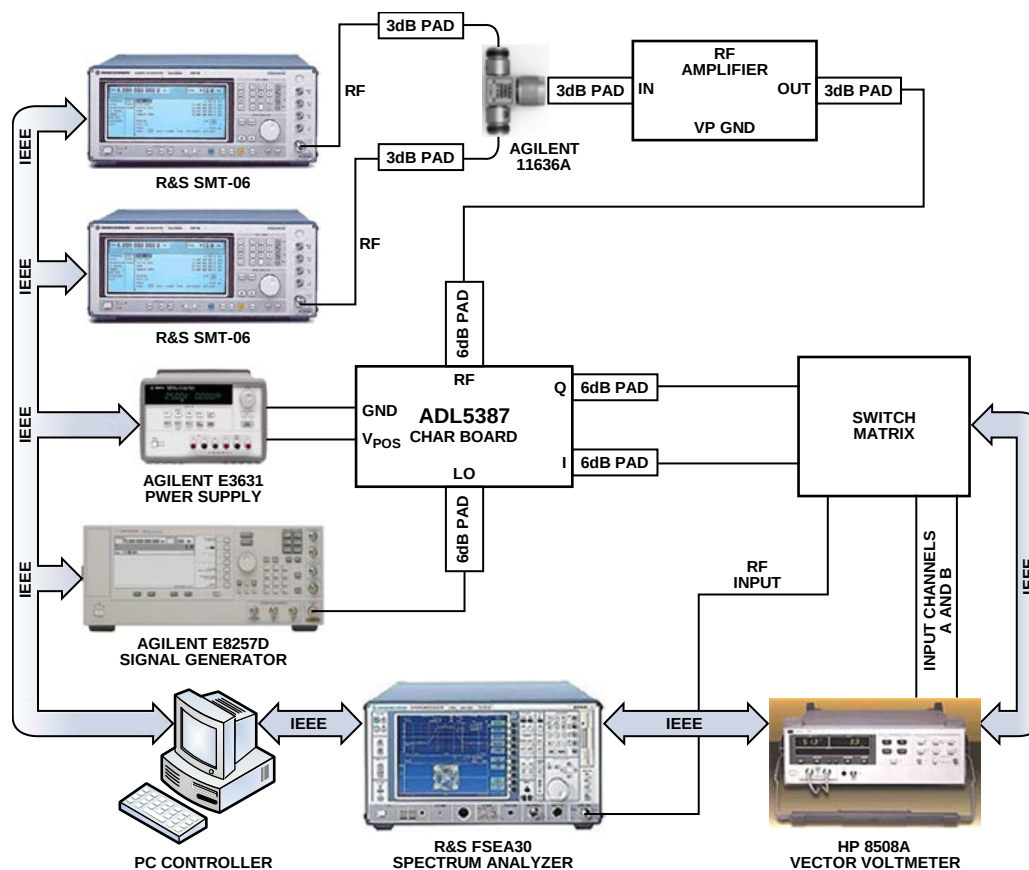


Figure 66. General ADL5387 Characterization Setup

EVALUATION BOARD

The [ADL5387](#) evaluation board is available. The board can be used for single-ended or differential baseband analysis. The default configuration of the board is for single-ended baseband analysis.

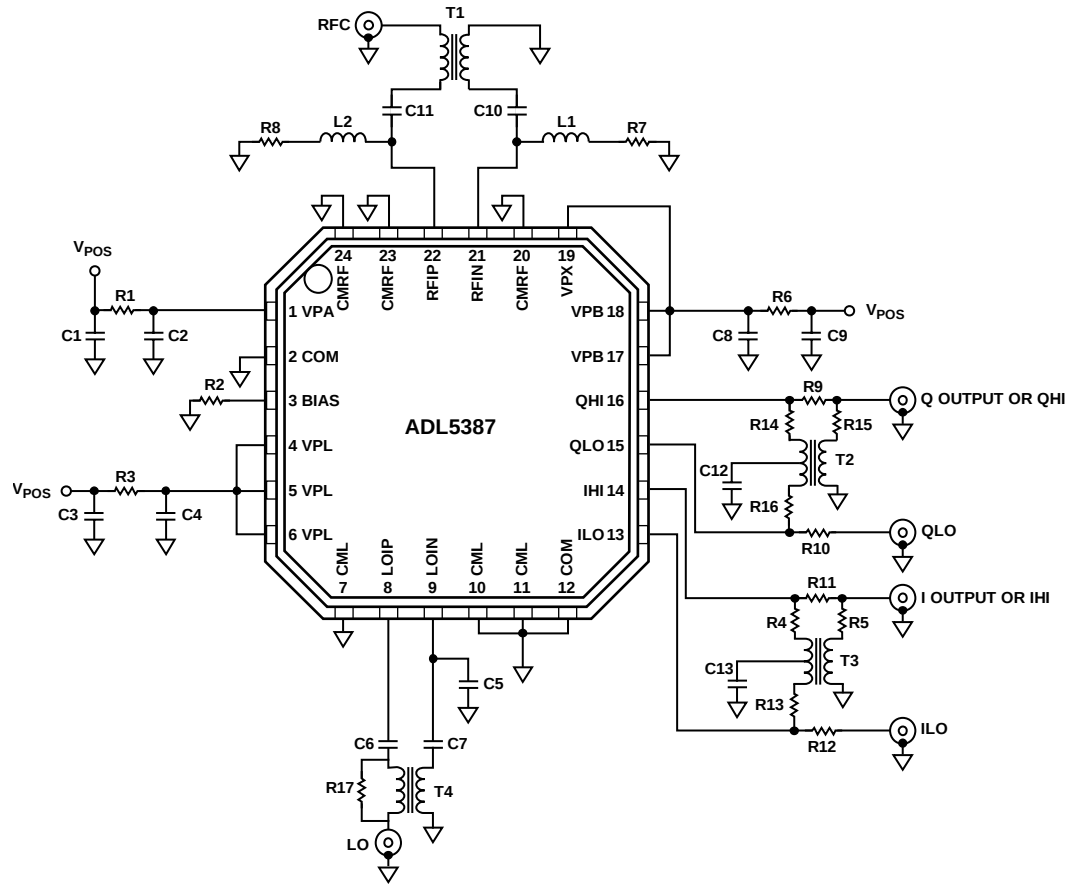
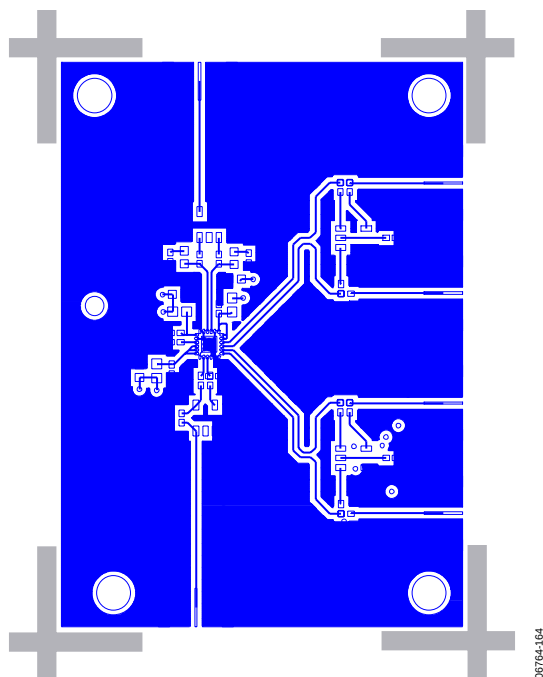


Figure 67. Evaluation Board Schematic

06764-060

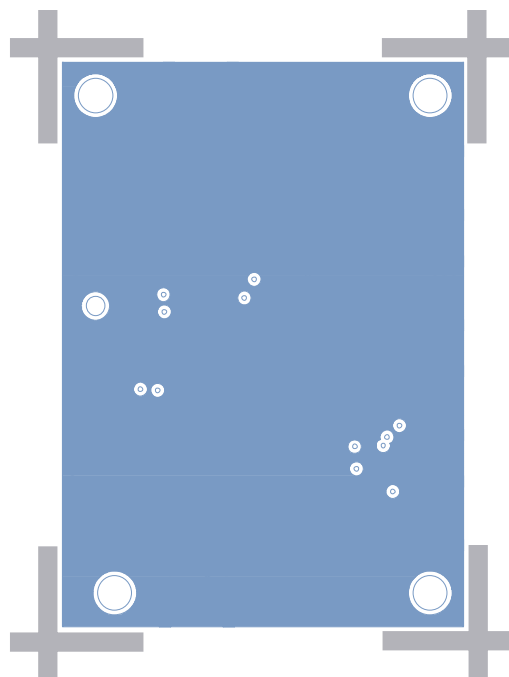
Table 4. Evaluation Board Configuration Options

Component	Function	Default Condition
VPOS, GND	Power Supply and Ground Vector Pins.	Not Applicable
R1, R3, R6	Power Supply Decoupling. Shorts or power supply decoupling resistors.	R1, R3, R6 = 0 Ω (0805)
C1, C2, C3, C4, C8, C9	The capacitors provide the required dc coupling up to 2 GHz.	C2, C4, C8 = 100 pF (0402) C1, C3, C9 = 0.1 μ F (0603)
C5, C6, C7, C10, C11	AC Coupling Capacitors. These capacitors provide the required ac coupling from 50 MHz to 2 GHz. For operation down to 30 MHz, C10 and C11 should be changed to 0.01 μ F.	C5, C6, C10, C11 = 1000 pF (0402), C7 = Open
R4, R5, R9 to R16	Single-Ended Baseband Output Path. This is the default configuration of the evaluation board. R14 to R16 and R4, R5, and R13 are populated for appropriate balun interface. R9, R10 and R11, R12 are not populated. Baseband outputs are taken from QHI and IHI. The user can reconfigure the board to use full differential baseband outputs. R9 to R12 provide a means to bypass the 9:1 TCM9-1 transformer to allow for differential baseband outputs. Access the differential baseband signals by populating R9 to R12 with 0 Ω and not populating R4, R5, R13 to R16. This way the transformer does not need to be removed. The baseband outputs are taken from the SMAs of Q_HI, Q_LO, I_HI, and I_LO.	R4, R5, R13 to R16 = 0 Ω (0402), R9 to R12 = Open
L1, L2, R7, R8	Input Biasing. Inductance and resistance sets the input biasing of the common base input stage. Default value is 120 nH for operation above 50 MHz. For operation down to 30 MHz, L1 and L2 should be changed to 680 nH.	L1, L2 = 120 nH (0402) R7, R8 = 0 Ω (0402)
T2, T3	IF Output Interface. TCM9-1 converts a differential high impedance IF output to a single-ended output. When loaded with 50 Ω , this balun presents a 450 Ω load to the device. The center tap can be decoupled through a capacitor to ground.	T2, T3 = TCM9-1, 9:1 (Mini-Circuits)
C12, C13	Decoupling Capacitors. C12 and C13 are the decoupling capacitors used to reject noise on the center tap of the TCM9-1.	C12, C13 = 0.1 μ F (0402)
R17	LO Input Interface. The LO is driven as a single-ended signal. Although, there is no performance change for a differential signal drive, the option is available by placing a transformer (T4, ETC1-1-13) on the LO input path.	R17 = 0 Ω (0402)
T1	RF Input Interface. ETC1-1-13 is a 1:1 RF balun that converts the single-ended RF input to differential signal.	T1 = ETC1-1-13, 1:1 (M/A COM)
R2	R _{BIAS} . Optional bias setting resistor. See the Bias Circuit section to see how to use this feature.	R2 = Open



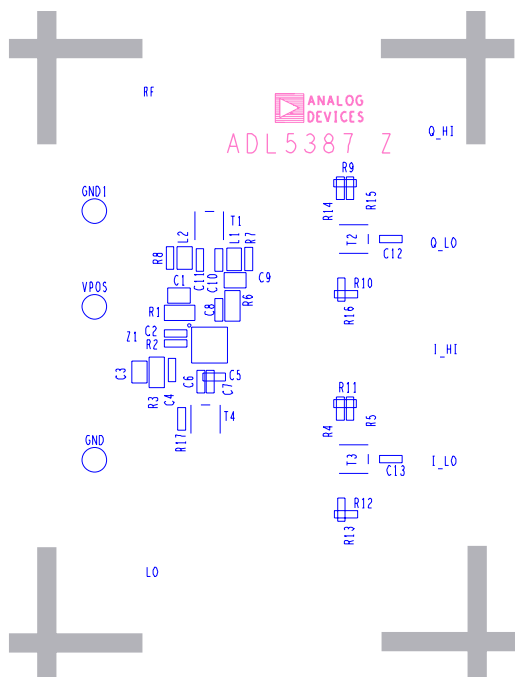
06764-164

Figure 68. Evaluation Board Top Layer



06764-166

Figure 70. Evaluation Board Bottom Layer



06764-165

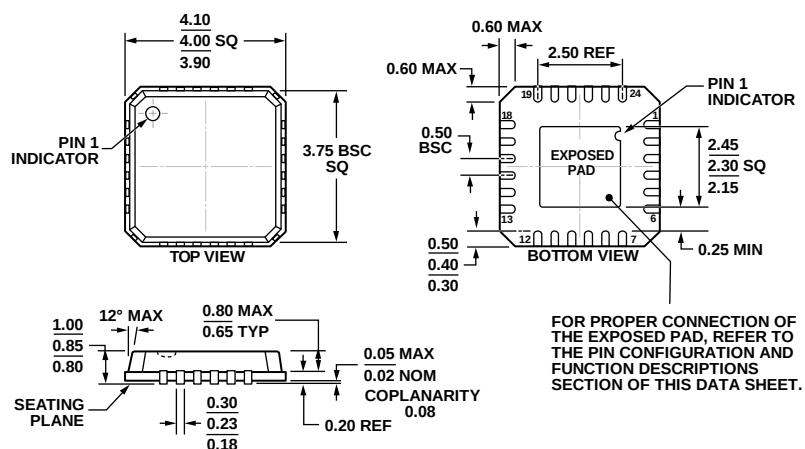
Figure 69. Evaluation Board Top Layer Silkscreen



06764-167

Figure 71. Evaluation Board Bottom Layer Silkscreen

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-220-VGGD-2

Figure 72. 24-Lead Lead Frame Chip Scale Package [LFCSP_VQ]
4 mm × 4 mm Body, Very Thin Quad
(CP-24-2)
Dimensions shown in millimeters

ORDERING GUIDE

Model ¹	Temperature Range	Package Description	Package Option	Ordering Quantity
ADL5387ACPZ-R2	–40°C to +85°C	24-Lead LFCSP_VQ	CP-24-2	250
ADL5387ACPZ-R7	–40°C to +85°C	24-Lead LFCSP_VQ, 7" Tape and Reel	CP-24-2	1,500
ADL5387ACPZ-WP	–40°C to +85°C	24-Lead LFCSP_VQ, Waffle Pack	CP-24-2	64
ADL5387-EVALZ		Evaluation Board		

¹ Z = RoHS Compliant Part.

NOTES

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[Analog Devices Inc.:](#)

[ADL5387ACPZ-R7](#) [ADL5387ACPZ-WP](#) [ADL5387-EVALZ](#)